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September 2014

# FJPF13009 NPN Silicon Transistor

#### **Features**

- High-Voltage Capability
- · High Switching Speed

# **Applications**

- Electronic Ballast
- Switching Regulator
- Motor Control
- Switched Mode Power Supply

# Description

The FJPF13009 is a 700 V, 12 A NPN silicon epitaxial planar transistor. The FJPF13009 is available with multiple  $h_{\text{FE}}$  bin classes for ease of design use. The FJPF13009 is designed for high speed switching applications which utilizes the industry standard TO-220F package offering flexibility in design and excellent power dissipation.



### **Ordering Information**

Part Number <sup>(1)</sup>	Top Mark	Package	Packing Method
FJPF13009H1TU	J13009-1	TO-220F 3L	Rail
FJPF13009H2TU	J13009-2	TO-220F 3L	Rail

#### Notes

1. The affix "-H1, H2" means the  $h_{\text{FE}}$  classification. The suffix "-TU" means the tube packing method.

### **Absolute Maximum Ratings**(2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at  $T_C = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	12	Α
I <sub>CP</sub>	Collector Current (Pulse)	24	Α
I <sub>B</sub>	Base Current	6	Α
P <sub>D</sub>	Total Device Dissipation (T <sub>C</sub> = 25°C)	50	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C

#### Note:

2. These ratings are based on a maximum junction temperature of 150°C. These are steady-state limits. Fairchild Semiconductor should be consulted on application involving pulsed or low-duty-cycle operations.

#### **Electrical Characteristics**

Values are at  $T_C = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max	Unit
V <sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage	$I_C = 10 \text{ mA}, I_B = 0$	400			V
I <sub>EBO</sub>	Emitter Cut-Off Current	$V_{EB} = 9 \text{ V}, I_{C} = 0$			1	mA
h <sub>FE1</sub>	DC Current Gain <sup>(3)</sup>	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ A}$	8		40	
h <sub>FE2</sub>	Do Current Gain	$V_{CE} = 5 \text{ V}, I_{C} = 8 \text{ A}$	6		30	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage <sup>(3)</sup>	$I_C = 5 A, I_B = 1 A$			1.0	
		I <sub>C</sub> = 8 A, I <sub>B</sub> = 1.6 A	- /		1.5	V
		I <sub>C</sub> = 12 A, I <sub>B</sub> = 3 A			3.0	/
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage <sup>(3)</sup>	I <sub>C</sub> = 5 A, I <sub>B</sub> = 1 A			1.2	V
	Base-Emitter Saturation Voltage	I <sub>C</sub> = 8 A, I <sub>B</sub> = 1.6 A			1.6	
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10 V, f = 0.1 MHz		180		pF
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}$	4			MHz
t <sub>ON</sub>	Turn-On Time	V <sub>CC</sub> = 125 V, I <sub>C</sub> = 8 A,			1.1	
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 1.6 \text{ A},$			3.0	μs
t <sub>F</sub>	Fall Time	$R_L = 15.6 \Omega$			0.7	

#### Note:

3. Pulse test: pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%

# **h**<sub>FE</sub> Classification

Classification	H1	H2
h <sub>FE1</sub>	8 ~ 17	15 ~ 28

# **Typical Performance Characteristics**

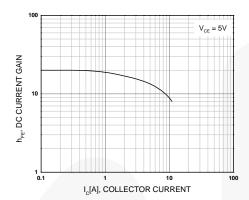


Figure 1. DC Current Gain

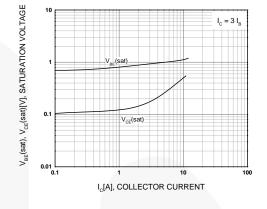


Figure 2. Base-Emitter Saturation Voltage and Collector-Emitter Saturation Voltage

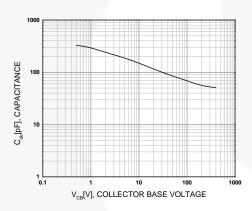


Figure 3. Collector Output Capacitance

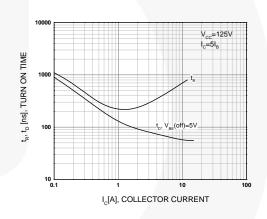


Figure 4. Turn-On Time

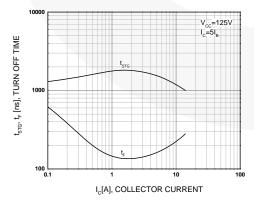


Figure 5. Turn-Off Time

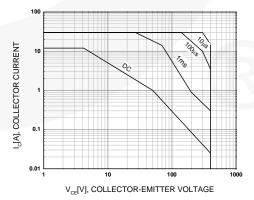


Figure 6. Forward Bias Safe Operating Area

# **Typical Performance Characteristics** (Continued)

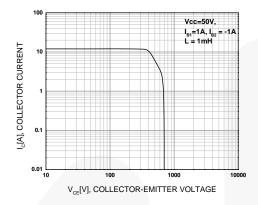


Figure 7. Reverse Bias Safe Operating Area

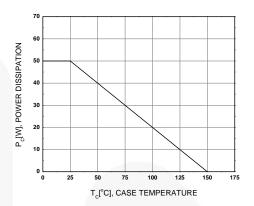
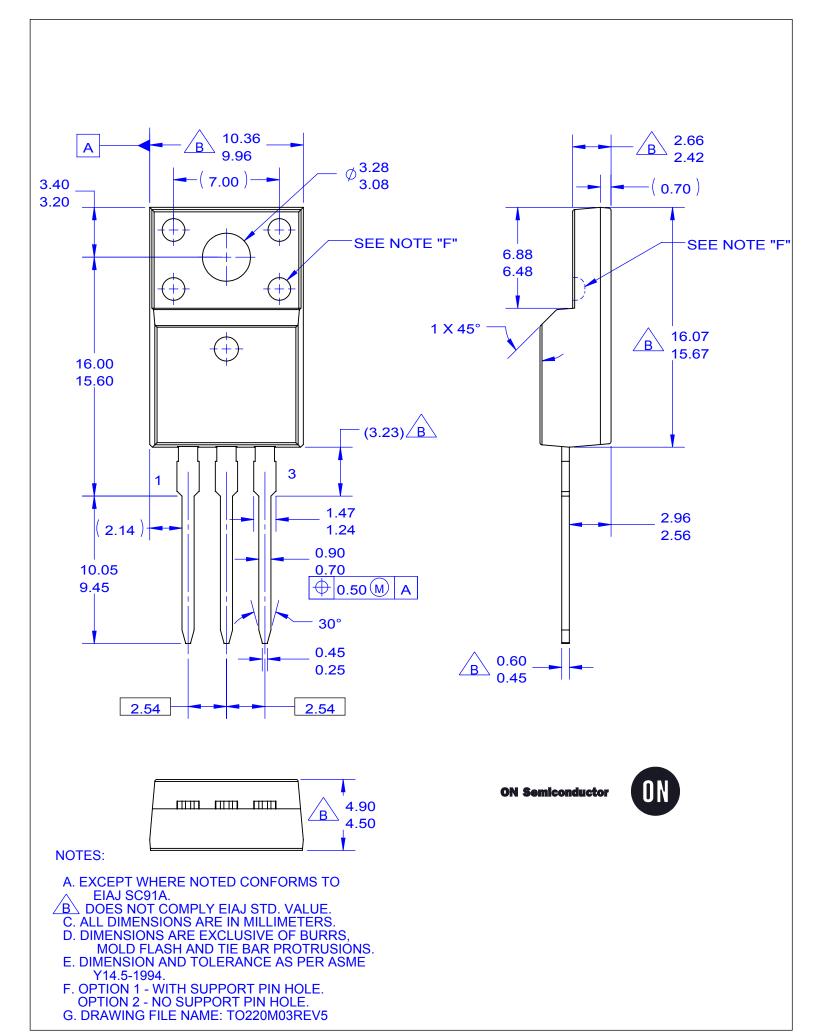


Figure 8. Power Derating



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